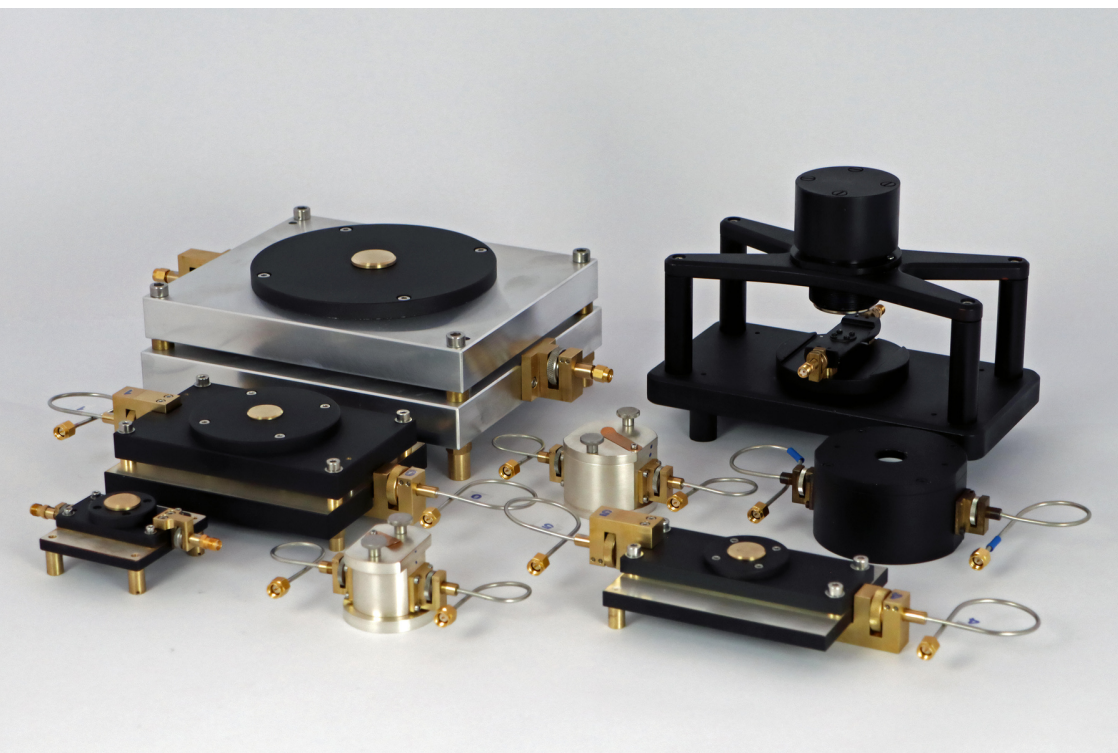


HARDWARE CATALOG



MICROWAVE MATERIAL TESTING

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Color Legend by materials:



Solid dielectrics



Liquid Dielectrics



Conductors



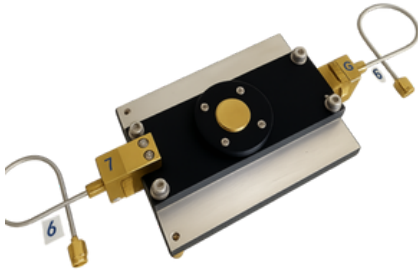
Semiconductors



Absorbers



Ferromagnetics



Dielectrics



SPDR non-destructively measures in-plane ϵ_r and $\tan \delta$ of flat dielectric sheets.

Polymers



The split-post resonator quantifies ϵ_r and $\tan \delta$ of low-loss polymer laminates and composites.

Ultra-Thin Films



Using a film-on-substrate approach, SPDR resolves micrometer-scale coatings by tracking tiny shifts in resonance frequency and Q-factor.

Highly-Resistive Semiconductors



SPDR measures ϵ_r and $\tan \delta$ of high-resistivity Si/SiC; if the loss is mainly conductive, it also yields bulk resistivity (ρ).

Parameters

- Frequency range: **1.1 – 15 GHz***
- Dielectric constant: **$D_k = 1 - 100$** (achievable accuracy $\pm 0.15\%$)
- Loss tangent: **$D_f > 2 \times 10^{-5}$** (achievable accuracy $\leq 2\%$)
- Resistivity: **$\rho = 10^2 - 10^4 \Omega \cdot \text{cm}$**
- Maximum sample thickness: **0.6 – 6 mm** (depends on frequency)
- Sample diameter: **14 – 120 mm** (depends on frequency)
- Measurement time: **< 30 seconds**
- Temperature: room, **0 – 110 °C**
- Supported standards: **IEC 61189-2-721 (04-2015); IPC-TM-650 2.5.5.15**
- Suitable for low-loss dielectrics, high-resistivity semiconductors & thin films
- Software-controlled measurement

*Each SPDR is manufactured for a single nominal frequency (1.1, 2.45, 5, 10 or 15 GHz). Other frequencies within 1.1 – 15 GHz are available on request.

Fabry - Perot Open Resonators for Dielectrics



Dielectrics



Non-contact FPOR measurements deliver ϵ and $\tan\delta$ of bulk dielectrics.

Polymers



The open resonator quantifies ϵ and $\tan\delta$ of low-loss polymer sheets without electrodes.

Ultra-Thin Films



FPOR resolves dielectric properties of films just a few μm thick by analysing minute Q-factor shifts,

Highly-Resistive Semiconductors



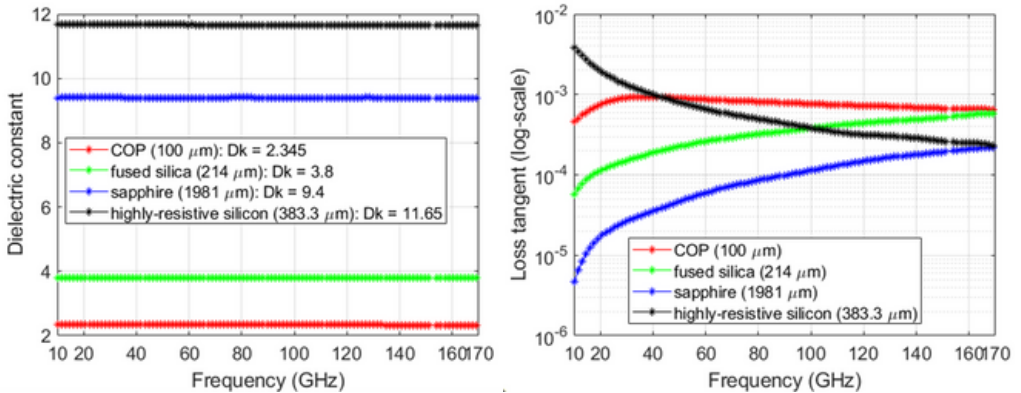
extracts bulk resistivity of semiconductors like Si or SiC.

Parameters

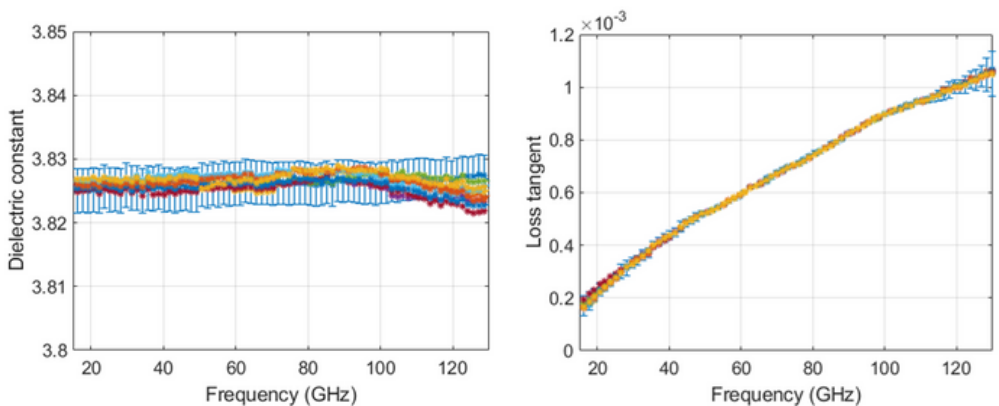
- Frequency range: **10 – 130 GHz***
- Dielectric constant: **$Dk = 1 - 15$ (achievable accuracy $\pm 0.25\%$)**
- Loss tangent: **$Df > 5 \times 10^{-6}$ (achievable accuracy $\pm 2\%$)**
- Sample thickness: **1 μm – 3 mm**
- Sample diameter: **50 – 150 mm**
- Measurement time: **> 1 minute**
- Temperature: **room, 0 – 80 °C (on request)**
- In-plane anisotropic materials can be measured
- Fully automated and software-controlled measurement

*Available also in various frequency-range configurations (e.g. 10 – 26.5 GHz, 10 – 43 GHz, 10 – 50 GHz, 10 – 67 GHz, 10 – 110 GHz, etc.)

Measurement Results

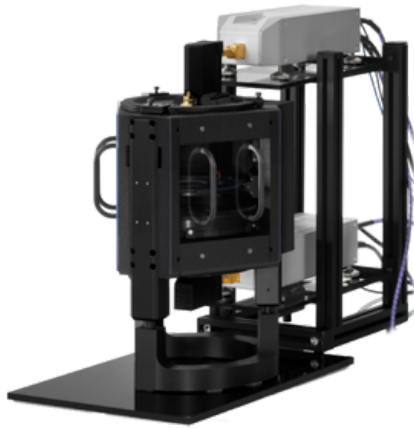


Overview of the FPOR measurement capabilities. Unique possibility of having a single measurement fixture for the whole 10–170 GHz range.



Fused silica wafer ($148.15 \pm 0.36 \mu\text{m}$) measured 10 times, each time removing and inserting the sample again. D_k uncertainty bars arise from thickness uncertainty; D_f bars from signal-to-noise ratio. Outstanding D_k repeatability of 0.15 %!

D-Band Fabry-Perot Open Resonator for Dielectrics



Dielectrics



Non-contact FPOR measurements deliver ϵ and $\tan\delta$ of bulk dielectrics.

Polymers



The open resonator quantifies ϵ and $\tan\delta$ of low-loss polymer sheets without electrodes.

Ultra-Thin Films



FPOR resolves dielectric properties of films just a few μm thick by analysing minute Q-factor shifts,

Highly-Resistive Semiconductors

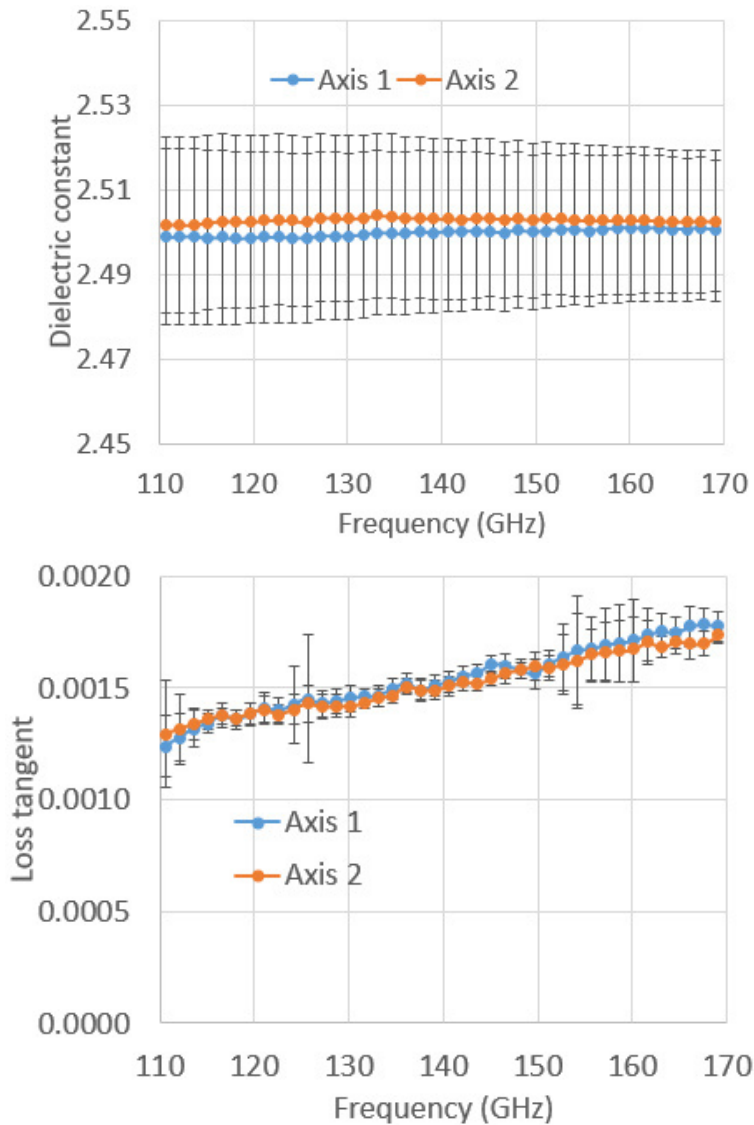


extracts bulk resistivity of semiconductors like Si or SiC.

Parameters

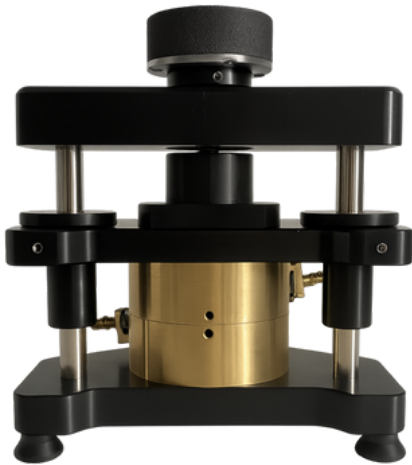
- Frequency range: **110 – 170 GHz**
- Dielectric constant: **$D_k = 1 - 15$** (achievable accuracy $\pm 0.5 \%$)
- Loss tangent: **$D_f > 5 \times 10^{-6}$** (achievable accuracy $\pm 5 \%$)
- Sample thickness: **1 μm – 3 mm**
- Sample diameter: **> 50 mm**
- Measurement time: **> 3 minutes**
- Temperature: **room**
- In-plane anisotropic materials can be measured
- Fully automated and software-controlled measurement

Measurement Results



Overview of the D-Band FPOR measurement capabilities.

Q-Choke Split Cylinder Resonator



Dielectrics

SPDR non-destructively measures in-plane ϵ_r and $\tan \delta$ of flat dielectric sheets.



Polymers

The split-post resonator quantifies ϵ_r and $\tan \delta$ of low-loss polymer laminates and composites.



Ultra-Thin Films

Using a film-on-substrate approach, SPDR resolves micrometer-scale coatings by tracking tiny shifts in resonance frequency and Q-factor.



Highly-Resistive Semiconductors

SPDR measures ϵ_r and $\tan \delta$ of high-resistivity Si/SiC; if the loss is mainly conductive, it also yields bulk resistivity (ρ).

Parameters

- Frequency range: **10 GHz** (higher frequencies coming soon...)
- Dielectric constant: **Dk = 1-15** (achievable accuracy $\pm 0.2\%$)
- Loss tangent: **Df > 5×10^{-6}** (achievable accuracy $\pm 2\%$)
- Sample size: **40 × 40 mm – 100 × 100 mm**
- Sample thickness: **5 μm to 4 mm** (e.g., sapphire)
- Supported standards: **IPC TM-650 2.5.5.13**
- Software-controlled measurement



Ceramics

Ultra low-loss materials



High dk testing

Microwave resonators, filters, etc.



Cryogenic temperatures

Uniquely accurate measurements at low temperatures



TCK & TCF extraction

Up to 125 °C or higher with custom-designs

Parameters

- Frequency range: **Depends on dielectric constant and dimensions of the sample**
- Dielectric constant: **Dk = 1 – 1000** (achievable accuracy < 0.2%)
- Loss tangent: **Df = 10⁻² – 10⁻⁴** (achievable accuracy < 2%)
- Temperature: **-270 °C – 125 °C** (higher temperature on request)
- Software-controlled measurement

Fabry-Perot Open Resonator for Liquids



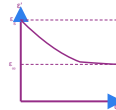
Electronic Coolant

highly sensitive measurement of ϵ_R and $\tan \delta$ in low-loss fluorinated liquids (e.g., Fluorinert FC-40).



Oil

broadband determination of complex permittivity for vegetable or lubricating oils.



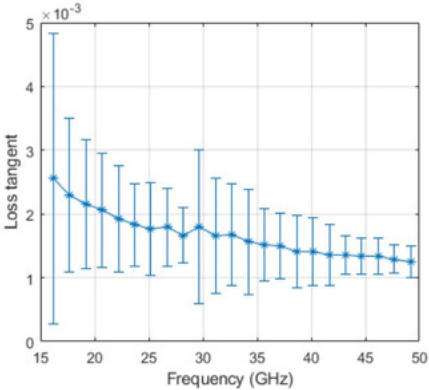
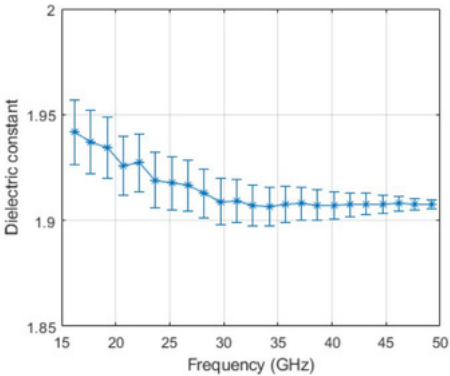
Dispersion

Reveal liquids hidden molecular dynamics by mapping how their dielectric constant and loss tangent change with frequency.

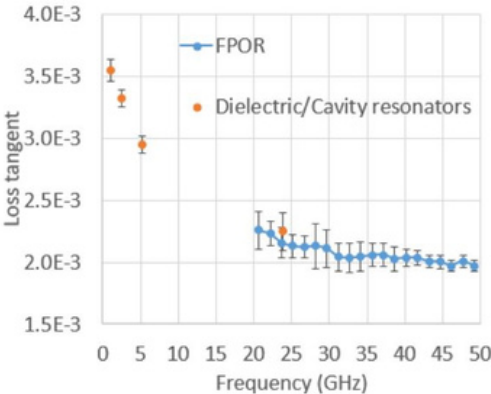
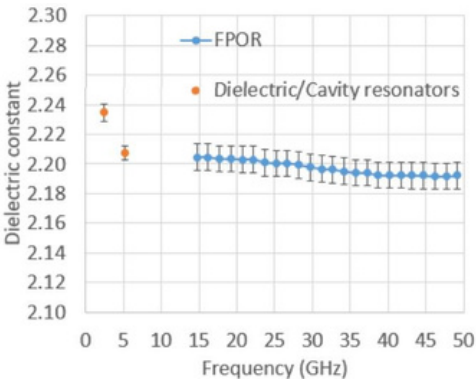
Parameters

- Frequency range: **15 – 67 GHz**
- Dielectric constant: **$Dk = 1 - 15$** (achievable accuracy < 0.5 %)
- Loss tangent: **$Df > 1 \times 10^{-4}$** (achievable accuracy < 2 %)
- Temperature: **room**
- Required fluid volume: **< 10 mL**
- Fully automated and software-controlled measurement

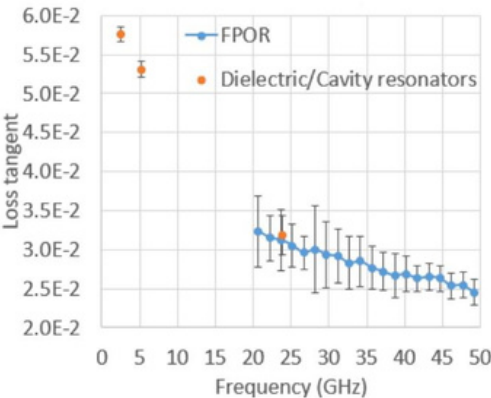
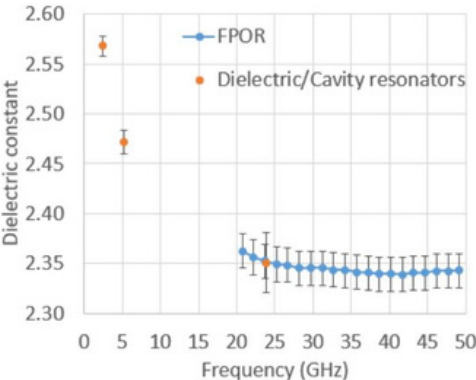
Measurement Results



FPOR for Liquid results for 3M Fluorinert FC-40.



FPOR for Liquid measurements of engine oil versus dielectric/cavity-resonator



FPOR for Liquid measurements of canola oil versus dielectric/cavity-resonator



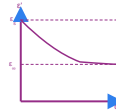
Electronic Coolant

highly sensitive measurement of ϵ_R and $\tan \delta$ in low-loss fluorinated liquids (e.g., Fluorinert FC-40).



Oil

broadband determination of complex permittivity for vegetable or lubricating oils.

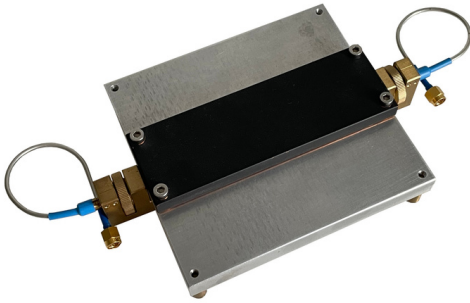


Dispersion

Reveal liquids hidden molecular dynamics by mapping how their dielectric constant and loss tangent change with frequency.

Parameters

- Frequency range: **1 GHz, 2.5 GHz, 5 GHz, 2.5 & 5 GHz, 10 GHz, 24 GHz**
- Dielectric constant: **Dk = 1 - 100** (achievable accuracy < 0.5 %)
- Loss tangent: **Df > 1×10^{-4}** (achievable accuracy < 2 %)
- Temperature: **0 - 100 °C**
- Software-controlled measurement



Conductive Composites



the dielectric properties of composite films just a few micrometers thick

Semiconductors



The SiPDR resonator extracts the bulk resistivity of semiconductor wafers (e.g., SiC) from $10 \text{ } \Omega \cdot \text{cm}$ up to several hundred $\Omega \cdot \text{cm}$.

Metamaterials



Contact-less SiPDR measurements deliver dielectric loss data for engineered negative-index metamaterial structures.

Parameters

- Frequency range: **5 GHz** (other bands on request)
- Resistivity (bulk) **$\rho = 10^{-4} - 10^3 \text{ } \Omega \cdot \text{cm}$** (accuracy $\pm 2 \%$)
- Surface resistance (thin films): **$R_s = 10^{-1} - 2 \times 10^4 \text{ } \Omega/\text{sq}$** (accuracy $\pm 2 \%$)
- Sample thickness: **few μm to 1 mm**
- Sample diameter: **30 – 90 mm**
- Measurement time: **$\ll 1$ minute**
- Temperature: **0 – 110 $^{\circ}\text{C}$**
- Suitable for lossy thin films, resistive layers & doped semiconductor wafers
- Software-controlled measurement

Fabry-Perot Open Resonator for Conductors



Bulk Metal

rigid sheets or plates of highly-conductive metals (e.g., copper, silver, aluminium).



Conductive Foils

thin, flexible metal foils such as rolled copper; the resonator probes their surface conductivity even at micrometre-level thicknesses.



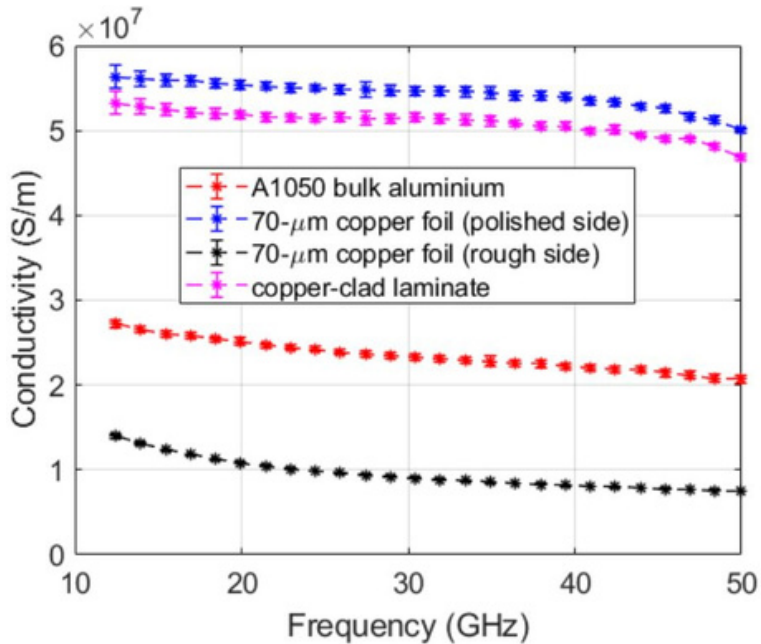
Copper-Clad Laminates

PCB-grade dielectric panels coated with copper; the instrument measures the electrical conductivity of the copper.

Parameters

- Frequency range: **12 – 50 GHz**
- Conductivity: **$\sigma = 5 \times 10^4 - 6 \times 10^7 \text{ S/m}$** (achievable accuracy < 5%)
- Sample thickness: **≥ 5 skin depths** (e.g., a few μm for Cu)
- Sample diameter: **150 – 195 mm**
- Measurement time: **a few minutes**
- Fully automated and software-controlled measurement

Fabry-Perot Open Resonator for Conductors



The FPOR for Conductors system measures conductive samples such as bulk aluminium, copper foils with different surface roughness, and copper-clad laminates across the 12 – 50 GHz range.



Bulk Metal

rigid sheets or plates of highly-conductive metals (e.g., copper, silver, aluminium).



Conductive Foils

thin, flexible metal foils such as rolled copper; the resonator probes their surface conductivity even at micrometre-level thicknesses.



Copper-Clad Laminates

PCB-grade dielectric panels coated with copper; the instrument measures the electrical conductivity of the copper.

Parameters

- Frequency range: **14 & 20 GHz or 28 & 44 GHz**
- Conductivity: **$\sigma = 10^5 - 6 \times 10^7 \text{ S/m}$**
- Sample thickness: **≥ 3 skin depths** (e.g., a few μm for Cu)
- Sample size: **$\geq 25 \times 25 \text{ mm}$**
- Software-controlled measurement



Spheres

The device is equipped is based on a novel electrodynamic model extracting ΔH of the material under test from the frequency and Q-factor of the magnetic-plasmon-resonance (MPR) of the sphere measured for a given vertical position of the magnet knob.

Parameters

- Frequency range: **5 – 9 GHz** (standard; extended 2 – 18 GHz*)
- Usable cavity range: **Up to ~60 GHz****
- Magnetic bias: Hand-held tunable magnet
- Sample diameter: **D < 0.6 mm**
- Linewidth capability (ΔH): **< 0.25 Oe @ 2 GHz**
< 5 Oe @ 5 GHz
< 30 Oe @ 18 GHz
- Temperature: **room**
- Software-controlled measurement

* Extended 2 – 18 GHz operation via spacer sleeves and cavity support changes.

** Cavity acts as a mechanical holder up to ~60 GHz; operation beyond 18 GHz requires stronger magnetic bias (e.g., external magnet).

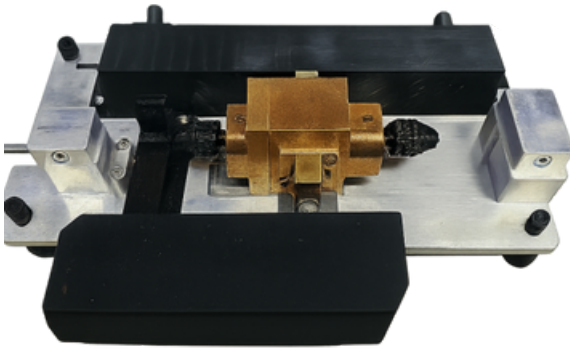


Spheres

The device is equipped is based on a novel electrodynamic model extracting ΔH of the material under test from the frequency and Q-factor of the magnetic-plasmon-resonance (MPR) of the sphere measured for a given vertical position of the magnet knob.

Parameters

- Nominal frequency: **5 GHz** (option: **10 GHz***)
- Magnetic bias: **Hand-held tunable magnet**
- Sample type: **Low-magnetic-loss ferrite spheres**
- Sample diameter: **$D < 1.5$ mm** (quartz tube holder)
- Temperature: **room**
- Measurability examples: **$\Delta H = 0.2$ Oe, $D = 0.5$ mm, $M_s = 1800$ Gs**
 $\Delta H = 3$ Oe, $D = 1.4$ mm, $M_s = 1200$ Gs
 $\Delta H = 16$ Oe, $D = 1.2$ mm, $M_s = 1700$ Gs
 $\Delta H = 20$ Oe, $D = 1.0$ mm, $M_s = 1800$ Gs
(no mode splitting)



Conductive Wires

Fast GHz cavity test for thin wires: clamp once, get conductivity (σ) and effective diameter in seconds.

Parameters

- Frequency range:
- Wire parameters:

from 37 GHz up to 70 GHz

Diameter: **100 – 450 μm**

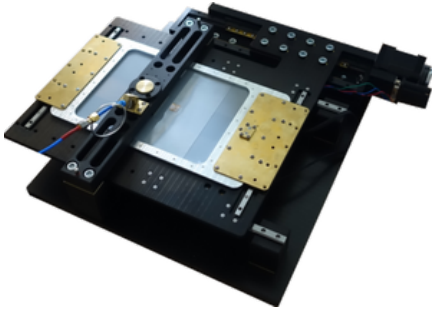
Length: **> 10 cm**

Conductivity: **$\sigma > 10 \text{ S/m}$**

Maximum achievable accuracy: **< 1%**

- Software-controlled measurement

2D Split-Post Dielectric Resonator



Dielectrics

SPDR non-destructively measures in-plane ϵ_r and $\tan \delta$ of flat dielectric sheets.



Polymers

The split-post resonator quantifies ϵ_r and $\tan \delta$ of low-loss polymer laminates and composites.



Ultra-Thin Films

Using a film-on-substrate approach, SPDR resolves micrometer-scale coatings by tracking tiny shifts in resonance frequency and Q-factor.

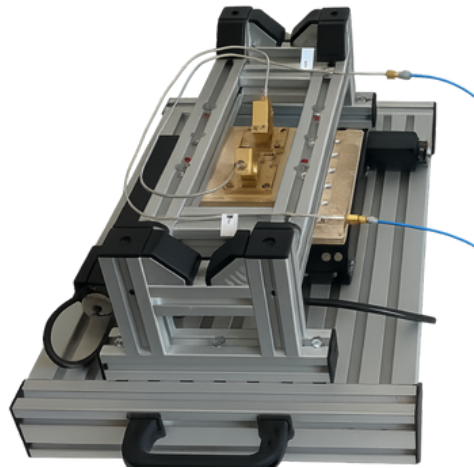


Higly-Resistive Semiconductors

SPDR measures ϵ_r and $\tan \delta$ of high-resistivity Si/SiC; if the loss is mainly conductive, it also yields bulk resistivity (ρ).

Parameters

- Frequency range: **10 GHz**
- Conductivity: **$0.1 - 10^6 \text{ 1}/(\Omega \cdot \text{m})$**
- Resistivity (bulk) **$\rho = 10^{-4} - 10^3 \Omega \cdot \text{cm}$**
- Surface resistivity (thin films): **$R_s = 10^{-1} - 2 \times 10^4 \Omega/\text{sq}$**
- Sample size: **up to $80 \times 120 \text{ mm}$**
- Sample thickness: **few μm up to 1 mm**
- Fully automated, software-controlled measurement



Conductive Composites



the dielectric properties of composite films just a few micrometers thick

Semiconductors



The SiPDR resonator extracts the bulk resistivity of semiconductor wafers (e.g., SiC) from $10^{-4} \Omega\cdot\text{cm}$ up to several hundred $\Omega\cdot\text{cm}$.

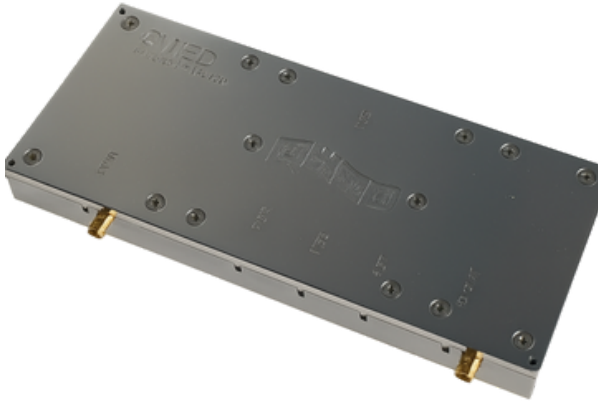
Metamaterials



Contact-less SiPDR measurements deliver dielectric loss data for engineered negative-index metamaterial structures.

Parameters

- Frequency range: **10 GHz**
- Resistivity (bulk) **$\rho = 10^{-4} - 10^3 \Omega\cdot\text{cm}$ (accuracy $\pm 2 \%$)**
- Surface resistance (thin films): **$R_s = 10^{-1} - 2 \times 10^4 \Omega/\text{sq}$ (accuracy $\pm 2 \%$)**
- Sample thickness: **few μm to 1 mm**
- Sample diameter: **up to 100 x 100 mm**
- Measurement time: **$\ll 1$ minute**
- Suitable for lossy thin films, resistive layers & doped semiconductor wafers
- Fully automated, software-controlled measurement



Fast & Easy testing

USB-connected Windows application provides real-time parameter adjustment.



SPDR & SiPDR dedicated

Portable material testing setup.



Alternative to VNA

For materials testing

Parameters

- Interface (data and power):
- Power consumption:
- Accuracy of measurement:
- Range of measured Q-factor:
- Frequency range:
- Frequency resolution:
- Frequency stability:
- Output power:
- Range of input power:

USB-C (connect to USB 3.0 port)

5 V, 900 mA

Q: 2% for Q > 1000 F: 2.5 ppm

200 ÷ 100 000

8.4 GHz ÷ 10.4 GHz

1 kHz

2.5 ppm

1 dBm ± 3 dBm

-80 dBm ÷ -30 dBm



Parameters

- Interface (data and power):
- Power consumption:
- Accuracy of measurement:
- Range of measured Q-factor:
- Frequency range:
- Frequency resolution:
- Frequency stability:
- Output power:
- Range of input power:
- Measurement time:



Fast & Easy testing

USB-connected Windows application provides real-time parameter adjustment.



SPDR & SiPDR dedicated

Portable material testing setup.



Alternative to VNA

For materials testing

Mini-USB (connect to USB port)

5 V, ~400 mA

ϵ : 1% for $Q > 1000$

$\Delta \tan \delta = \pm 2 \cdot 10^{-5}$ or $\pm 0.03 \cdot \tan \delta$

200 ÷ 100 000

Type 1: 4.4 GHz ÷ 5.2 GHz,

Type 2: 1.4 GHz ÷ 2.6 GHz,

Type 3: 0.7 GHz ÷ 1.3 GHz

1 kHz

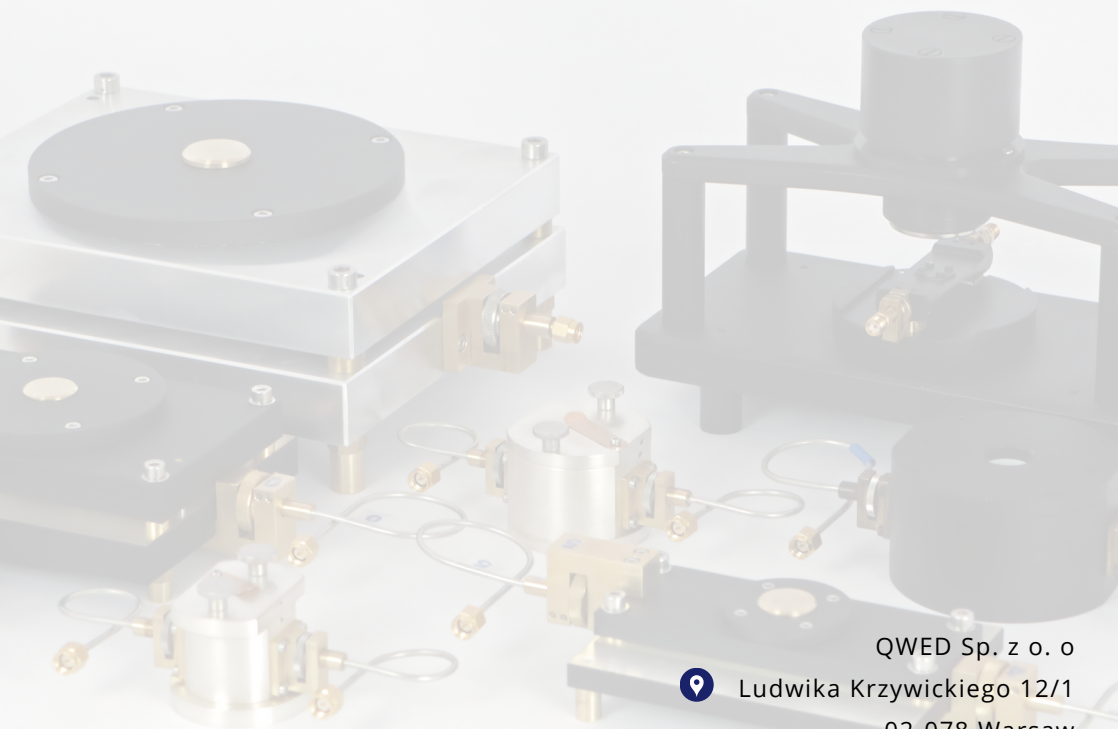
2.5 ppm

12 dBm ± 3 dBm

-55 dBm ÷ -5 dBm

< 10 s

MICROWAVE MATERIAL TESTING



QWED Sp. z o. o



Ludwika Krzywickiego 12/1

02-078 Warsaw



info@qwed.eu



<https://www.qwed.eu>

www.qwed.eu

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